TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSIV)

TPCF8104

Notebook PC Applications Portable Equipment Applications

- Low drain-source ON resistance: $R_{DS (ON)} = 21 \text{ m}\Omega \text{ (typ.)}$
- High forward transfer admittance: |Y_{fs}| = 9.6 S (typ.)
- Low leakage current: $I_{DSS} = -10 \mu A \text{ (max)} (V_{DS} = -30 \text{ V})$
- Enhancement mode: $V_{th} = -0.8$ to -2.0 V ($V_{DS} = -10$ V, $I_D = -1$ mA)

Absolute Maximum Ratings (Ta = 25°C)

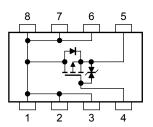
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Characteristics			Symbol	Rating	Unit
Drain-source voltage			VDSS	-30	<\K
Drain-gate voltage (R _{GS} = 20 kΩ)			VDGR)) –30	V
Gate-source voltage			VGSS	±20	\ V
Danie	DC	(Note 1)		-6	
Drain current	Pulse	(Note 1)	DP	-24	
Drain power dissipation	on /	(t = 5 s) (Note 2a)	PD	2.5	\rangle_{W}
Drain power dissipation (t = 5 s) (Note 2b)			√ P _D	0.7	W
Single pulse avalanch	ne energ	y (Note 3)	EAS	5.8	mJ
Avalanche current			I _{AR}	-3	Α
Repetitive avalanche energy/ (Note 4)			FAR	0.25	mJ
Channel temperature			√ ch	150	°C
Storage temperature range			Tstg	-55 to 150	°C
		<u> </u>			

Unit: mm

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Weight: 0.011 g (typ.)

Circuit Configuration



Note: (Note 1), (Note 2), (Note 3) and (Note 4): See the next page.

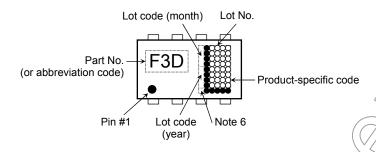
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Please handle with caution.

Thermal Characteristics

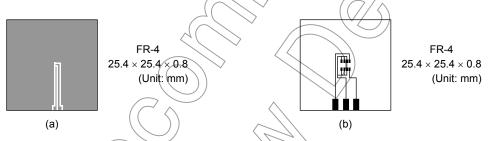
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 5 s) (Note 2a)	R _{th (ch-a)}	50.0	°C/W
Thermal resistance, channel to ambient (t = 5 s) (Note 2b)	R _{th (ch-a)}	178.6	°C/W

Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



Note 3: $V_{DD} = -24 \text{ V}$, $T_{ch} = 25^{\circ}\text{C}$ (initial), L = 0.5 mH, $R_{G} = 25^{\circ}\Omega$, $I_{AR} = -3.0 \text{ A}$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: • on the lower left of the marking indicates Pin 1.

Note 6: A dot marking identifies the indication of product Labels.

Without a dot: [[Pb]]/INCLUDES > MCV

With a dot: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

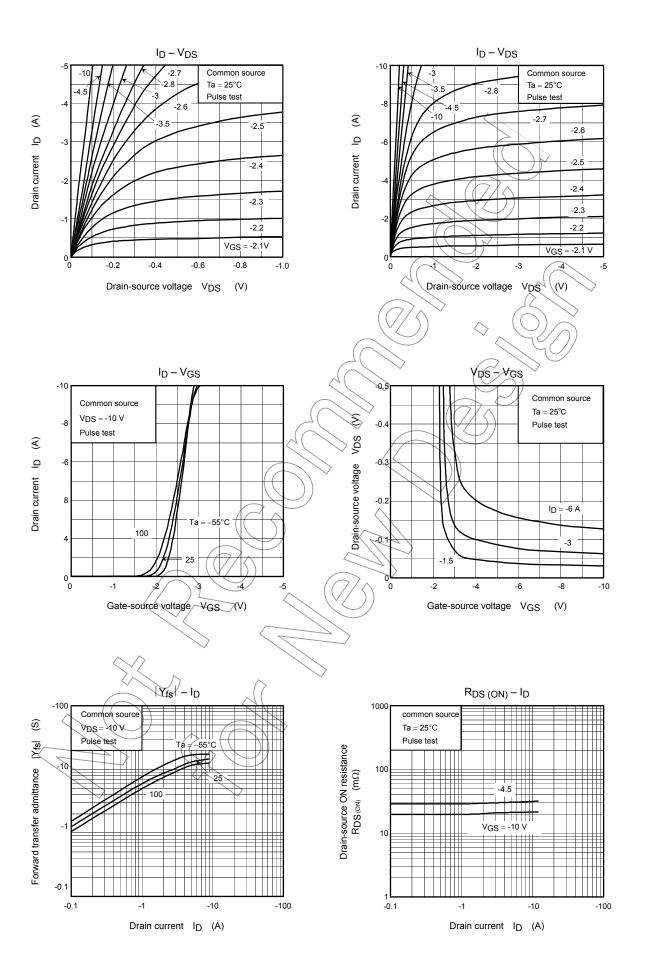
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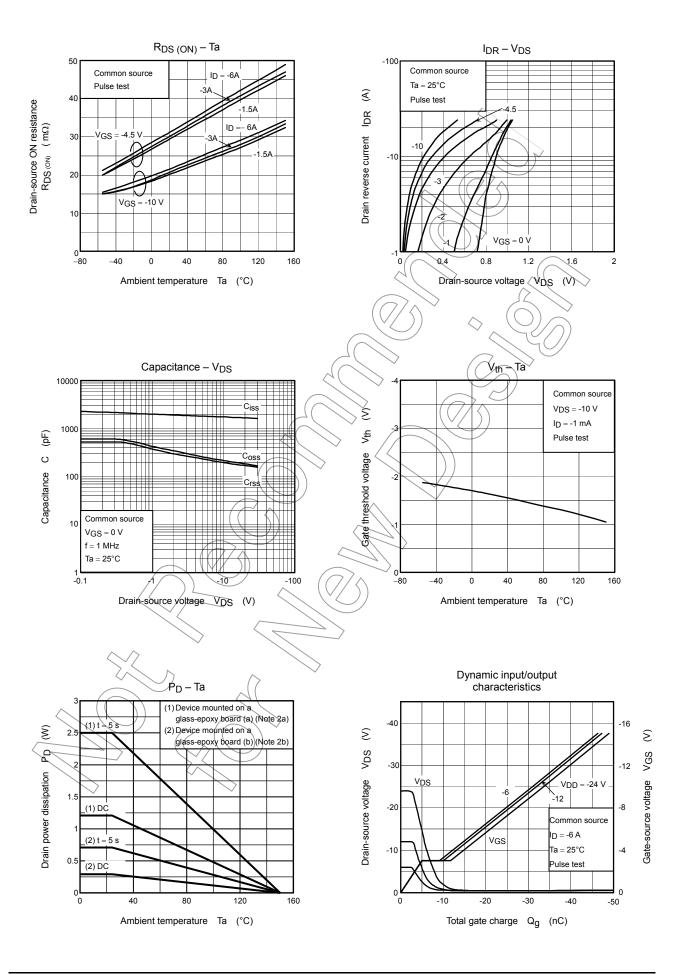
Electrical Characteristics (Ta = 25°C)

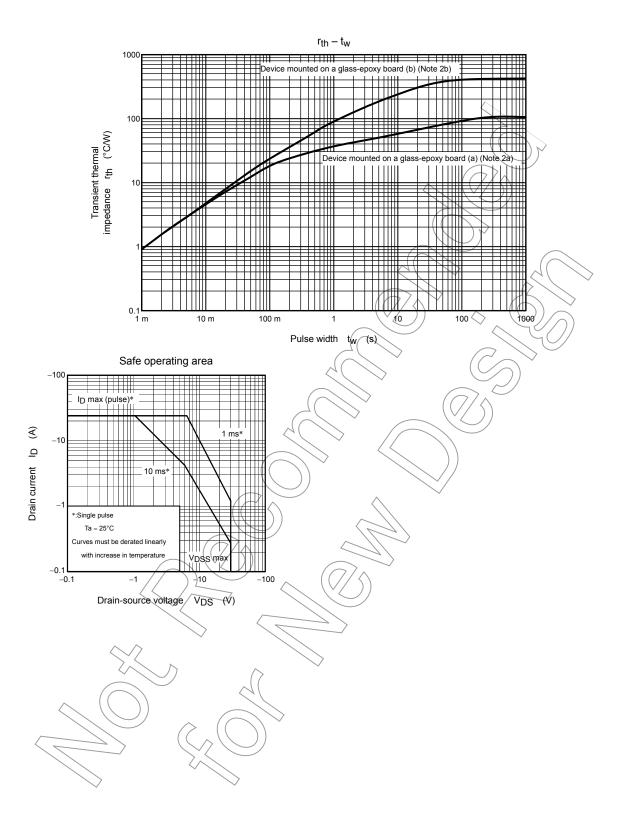
Ch	aracteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage cui	rent	I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±10	μΑ	
Drain cut-off curr	ent	I _{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$	_	_	-10	μА	
Drain-source breakdown voltage		V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30	_	_	V	
Diaiii-souice bie	akdowii vollage	V (BR) DSX	$I_D = -10 \text{ mA}, V_{GS} = 20 \text{ V}$	15 — —		_	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Gate threshold ve	oltage	V _{th}	$V_{DS} = -10 \text{ V}, I_D = -1 \text{mA}$	0.8) /~	-2.0	V	
Desir course ON excistence		R _{DS} (ON)	$V_{GS} = -4.5 \text{ V}, I_D = -3.0 \text{ A}$	<u> </u>	29	38	- mΩ	
Diain-source ON	Orain-source ON resistance Forward transfer admittance		$V_{GS} = -10 \text{ V}, I_D = -3.0 \text{A}$))	21	28		
Forward transfer	admittance	Y _{fs}	$V_{DS} = -10 \text{ V}, I_D = -3.0 \text{A}$	4.8	9.6	_	S	
Input capacitance	Input capacitance			_	1760	_		
Reverse transfer capacitance		C _{rss}	$V_{DS} = -10 \text{ V}, V_{GS} \neq 0 \text{ V}, f = 1 \text{ MHz}$	_	200	_	pF	
Output capacitance		Coss			210	\nearrow		
	Rise time	t _r	V _{GS} 0 V 7 V _D = 3.0 A	-(2.8	> _		
0 11 11	Turn-on time	t _{on}	VGS OVOUT		12	_		
Switching time	Fall time	t _f	R R R R R R R R R R	(\mathcal{A})	22	_	ns	
	Turn-off time	t _{off}	$V_{DD} \simeq -15 V$ Duty $\leq 1\%$, $t_W = 10 \mu s$) —	90	_		
Total gate charge (gate-source plus		Qg	V _{DD} ≈ -24 V, V _{GS} ≥ -10V,	_	34			
Gate-source charge1		Q _{gs1}	$I_D = -6.0 \text{ A}$	_	4.7		nC	
Gate-drain ("mille	er") charge	Qgd		_	7.2	_		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Charact	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	I _{DRP}		_	_	-24	А
Forward voltage	(diode)	V _{DSF}	$I_{DR} = -6.0 \text{ A}, V_{GS} = 0 \text{ V}$	_		1.2	V







6 2009-09-29

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